

Specification

Project Code : 3H501-V01

Product :1135nm 32mil-552E

Confidential

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Specification

`The specification applies to GaAs infrared chip for <u>1135nm</u> wavelength range.

The <u>**3H501-V01**</u> is a <u>**1135**</u>nm <u>**32**</u> mil Vertical Cavity Surface Emitting Laser (VCSEL) chip. The product characterized by the IR light wavelength and unique oxide-confined process of VCSELs.

Features

- Wavelength: 1135nm
- Chip size: 835 x 835 ± 15 μm
- Chip thickness : 150 ± 15 μm
- Drive current : 5A
- Output power : 2.8W @ pulse width 10μs, Duty 1% @ 5A
- Electrode side : Gold alloy on both anode P(emission side) and cathode N(backside)
- Other configurations available on request

Electrical Optical Characteristics (Pulse Width:10µs, Duty: 1%)

Applications

- Moving sensor/ Gesture
- Optical encoders
- 3D sensing
- Health or medical product
- Mobile and consumer
- D-TOF

TA = 25°C unless otherwise noted						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Condition
Threshold Current	lth	300	500	800	mA	lf =5A
Output Power	Ро	2600	2800	-	mW	lf =5A
Forward Voltage	Vf	2.5	2.7	2.9	v	If =5A
Slope Efficiency (S.E.)	ηs	0.60	0.65	0.70	W/A	lf =5A
Center Wavelength	λς	1125	1135	1145	nm	lf =5A
Power Conversion Efficiency	PCE	20	-	-	%	lf =5A
Wavelength Shift	<i>∆λ/</i> ∆T	-	0.07	-	nm/°C	lf =5A
Beam Divergence	θ	18	22	26	deg.	Full Width 1/e ²

Note 1: Forward Voltage (V_f) measurement allowance is ±0.1V.

Note 2: Center Wavelength (λ_c) measurement allowance is ±2.0nm.

Note 3: Others measurement allowance is ±10%.

Note 4: Wafer on probe system test and chip mounted on Cu star board, and measured with operating bias current (If) @ 5A @ Pulse Width (PW):10 μ s, Duty Cycle (DC): 1%.

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Typical Performance Curves

Typical Electrical-Optical Characteristics (T_a = 25°C, pulse width: 10μs, Duty 1%)



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Product :1135nm 32mil







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Other Information

RoHs Compliance:

HLJ committed to environment protection and sustainable development, this part complies with EU 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) and the relevant of held as part of our controlled documentation.

Packaging Q'ty:

500 ea/ die sheet, 8 die sheet/pack, 6 pack/ box, 6 box/ cargo box

ESD Protection:

VCSEL is very sensitive to Electrostatic discharge (ESD) and Electrical over stress (EOS), excessive ESD have damage the chip and result in performance degradation. Make sure during the whole usage and installation process that no ESD exist and electrical circuits are equipped with surge protection.

Important Notice:

The data provided in this data sheet shall be typical. In accordance with the HLJ policy of continuous improvement, specifications may change without notice.

Revision History

Revision	Description	Author	Release Date
1.0	Establish a Datasheet	Jerry	2023/11/19
1.1	Establish a Datasheet	Jerry	2024/3/12
1.2	Spec. Table adjunction (Ith. SE. PCE)	Jerry	2024/3/21

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